

DECLARATION

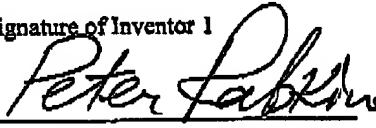
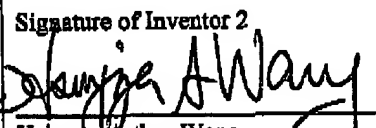
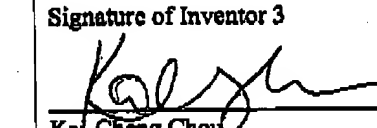
As a below named inventor, I declare that:

My residence, post office address and citizenship are as stated below next to my name; I believe I am an original, first and joint inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled: **PROCESSES AND STRUCTURES FOR SELF-ALIGNED CONTACT NON-VOLATILE MEMORY WITH PERIPHERAL TRANSISTORS EASILY MODIFIABLE FOR VARIOUS TECHNOLOGIES AND APPLICATIONS** the specification of which was filed on August 10, 2001 as Application No. 09/927,303.

I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above. I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, Section 1.56.

Full Name of Inventor 1:	Last Name: RABKIN	First Name: PETER	Middle Name or Initial:	
Residence & Citizenship:	City: Cupertino	State/Foreign Country: California	Country of Citizenship: United States	
Post Office Address:	Post Office Address: 21631 Regnart Road	City: Cupertino	State/Country: California	Postal Code: 95014
Full Name of Inventor 2:	Last Name: WANG	First Name: HSINGYA	Middle Name or Initial: Arthur	
Residence & Citizenship:	City: San Jose	State/Foreign Country: California	Country of Citizenship: United States	
Post Office Address:	Post Office Address: 295 Cresta Vista Way	City: San Jose	State/Country: California	Postal Code: 95119
Full Name of Inventor 3:	Last Name: CHOU	First Name: KAI-CHENG	Middle Name or Initial:	
Residence & Citizenship:	City: San Jose	State/Foreign Country: California	Country of Citizenship: Taiwan	
Post Office Address:	Post Office Address: 3661 Jasmine Circle	City: San Jose	State/Country: California	Postal Code: 95135

I further declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

Signature of Inventor 1 	Signature of Inventor 2 	Signature of Inventor 3 
P ter Rabkin	Hsingya Arthur Wang	Kai-Cheng Chou
Date 10/17/01	Date 10/17/01	Date 10/17/01